NSN 5961-01-231-1411

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-231-1411 **Inclosure Material:** Glass **Overall Length:** 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.076 inches **End Application:** 5820-01-081-5407 amplifier-conve **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 0.4 forward voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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